

PTM-40X-B PTM-40X-BP

Projection Blue and BluePump LED



Features

Ordering Information2
Binning Structure3
Typical Device Performance4
Absolute Maximum Ratings5
Optical & Electrical Characteristics6
Angular Distribution and Spectrum
Mechanical Dimensions9
Packaging Information 10
Solder Profile 12
Notes 13
Revision History 14

- Blue and BluePump LED with 4.0 mm² emitting area designed for display or other high performance applications.
- Complement with PTM-40X Red Amber and Converted Green for best projection brightness and color gamut
- Dominant wavelength: Blue 453 nm , BluePump 448 nm
- LED die precision mounted on Ultra low thermal resistance MC-PCB package.
- Thermistor pad allows option for precise thermal management
- Supports up to 12 A for highest brightness.
- Chipset array in series enabling lower drive current
- Windowless package allows for closer collection optics and brighter system solutions.
- LED emitting area optimized for micro-display diagonal sizes ranging from 0.45" to 0.55"
- Environmentally friendly: RoHS and REACH compliant

Applications

- Specifically engineered for ultra portable ("Pico") front projectors, head-up projection displays, and hybrid projectors
- Suitable for DLP[™], LCoS and HTPS /3LCD microdisplays

1



Ordering Information

Part Number Nomenclature

PTM –	– 40X –	- ## -	– L34 –	
Product Family	Chip Area & Technology	Color	Package Configuration ¹	Bin kit ²
PTM: Projection Technology Multi-Die	40: 4.0 mm² X: Isolated	B: Blue BP: Blue Pump	L34: No Connector 1.52mm thick core board 27 mm x 15.5 mm Windowless (See Mechanical Drawing section)	Refer to Bin kit Order Codes

Note 1: Ordering part numbers represent bin kits (group of bins that are shippable for a given ordering part number) Note 2: See Bin Kit and Flux / Power bin definitions on page 3

Ordering Part Numbers

Color Bi	Dia kit Ordanian Cada 3	Radior	netric Flux	Ware law oth Dire	Ordering Part Numbers
	Bin kit Ordering Code ³	Minimum Flux Bin	Minimum Flux/Power	Wavelength Bin	
D	EPD	4D	12.5	B1, B2	PTM-40X-B-L34-EPD
В —	EPE	4E	13.3	B1, B2	PTM-40X-B-L34-EPE
	EPE	4E	13.3	B0, B1	PTM-40X-BP-L34-EPE
BP -	EPF	4F	14.2	B0, B1	PTM-40X-BP-L34-EPF

Note 1: Ordering Part number is default to L34 package configuration.

Note 2: A Bin Kit represents a group of individual flux or power bins that are shippable for a given ordering part number. Individual flux bins are not orderable. EXAMPLE: PTM-40X-B-L34-EPD is comprised of Flux Bins 4D, 4E, 4F, 4G, 4H and 4J.



Binning Structure

Radiometric Flux Bins

Bin	Minimum Power (W)	Maximum Power (W)
4D	12.5	13.3
4E	13.3	14.2
4F	14.2	15.5
4G	15.5	17.0
4H	17.0	18.4
4J	18.4	19.9

Dominant Wavelength Bins

Bin	Minimum Dominant Wavelength (nm)	Maximum Dominant Wavelength (nm)
ВО	441	447
B1	447	450
B2	450	460

Note 1: Test condition at drive current 8.0 A, 20 ms single pulse at $T_c = 25^{\circ}C$.

Note 2: Luminus maintains a test measurement accuracy for LED flux and power of +/-6%.

Note 3: Wavelength bins are not orderable. Wavelength bins are displayed in product label.



Optical & Electrical Characteristics

Optical and Electrical Characteristics at 8.0 A, 20ms single pulse, 25°C

General Characteristics		Symbol	Blue	Blue Pump	Unit
Active Emitting Area	typ		4.03	4.03	mm ²
Total LED Array Dimensions	typ		2.7 x 1.55	2.7 x 1.55	mm x mm
Characteristics at Recommended Test Di	ive Curr	ent , I _f ^{1, 2}			
Test Pulse Duration			20	20	msec
Test Peak Drive Current ¹	typ	I _F	8.0	8.0	A
Peak Luminuous Flux ¹	typ	Φ,	490	400	lm
Peak Radiometric Flux ¹	typ	Φ _r	18.3	18.9	W
	min	λ_{dmin}	447	441	
Dominant Wavelength	typ	λ _d	453	448	
	max	λ_{dmax}	460	450	nm
Peak Wavelength	typ	λ _P	445	439	
FWHM- Spectral bandwidth at 50% of Φ_{r}	typ		21	21	
Chromaticity Coordinates ²	typ	x	0.15	0.16	CIE x
Chromaticity Coordinates	typ	у	0.02	0.02	CIE y
	min	V _{F min}	6.8	6.8	
Forward Voltage	typ	V _F	7.0	7.0	V
	max	V _{F max}	8.0	8.0	
Real thermal resistance ³ (junction - board)	typ	R _{th J-B real}	1.10	1.10	°C/W
Electrical thermal resistance ³ (junction - board)	typ	R _{th J-B}	0.75	0.75	°C/W

Note 1: All ratings are based on testing conditions with a constant heat sink temperature $T_{hc} = T_{p} = 25^{\circ}C$.

Note 2: CIE 1931 chromaticity diagram coordinates, normalized to X+Y+Z=1.

Note3: Thermal resistance values are based on modeled results correlated to measured R_{th J-hs} data using Forward Voltage sensitivity parametric method, compliant with JEDEC Standards JESD51-14



Optical & Electrical Characteristics

Absolute Maximum Ratings

	Symbol	Blue & Blue Pump	Unit
Absolute Maximum Reverse Drive Current (CW or Pulsed) ¹		0, Reverse Current Operation not allowed	
Absolute Minimum Current (CW or Pulsed) ¹		200	mA
Absolute Maximum Current (CW) ²		10.0	
Absolute Maximum Current (Pulsed) ^{2,3} (frequency > 240Hz, duty cycle <70%)		12.0	А
Absolute Maximum Surge Current ^{2,3} (Frequency > 240 Hz, duty cycle =10%, t=1ms)		13.0	
Absolute Maximum Junction Temperature ⁴	T _{jmax}	150	°C
Storage Temperature Range		-40 / +100	ىر
ESD sensitivity ANSI/ESDA/JEDEC JS-001 (HBM, Class 3A)	V _{ESD}	4000	V

Note 1: Product performance and lifetime data is specified at recommended forward drive currents. Sustained operation at or near absolute minimum currents may result in a reduction of device performance and device lifetime compared to recommended forward currents.

Note 2: Sustained operation above maximum currents is not recommended and will result in a reduction of device lifetime compared to specified maximum forward drive currents. Device lifetimes will depend on junction temperature

Note 3: In pulsed operation, rise time from 10 to 90% of forward current should be larger than 0.5 microseconds.

Note 4: Sustained operation at or above Maximum Operating Junction Temperature (T_{imax}) will result in significant reduction in device lifetime.

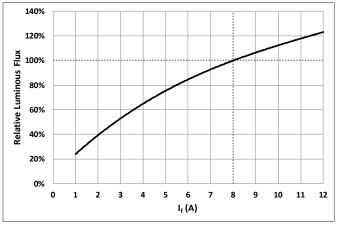


PTM-40X-B/BP

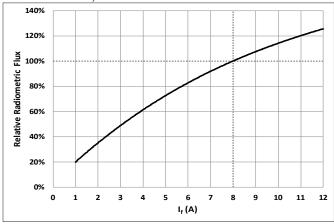
Product Datasheet

Optical and Electrical Characteristics

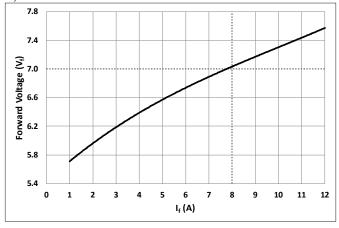
Relative Luminous Flux vs. Forward Current $\Phi_v(I_p)/\Phi_v(8.0 \text{ A}), T_j = 25^{\circ}\text{C}, \text{ Pulse duration 20 ms}$



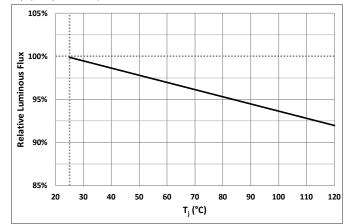
Relative Radiometric Flux vs. Forward Current $\Phi_{v}(I_{f})/\Phi_{v}(8.0 \text{ A}), T_{i} = 25^{\circ}\text{C}, \text{Pulse duration 20 ms}$



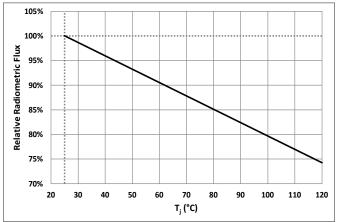
Forward Voltage vs. Forward Current $T_i = 25^{\circ}$ C, Pulse duration 20 ms



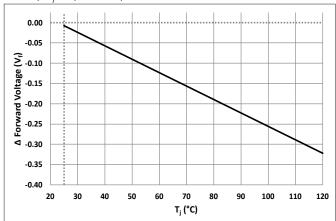
Relative Luminous Flux vs. Temperature $\Phi_v(I_f)/\Phi_v(25^{\circ}C), I_f = 8.0 A, Pulse duration 20 ms$



Relative Radiometric Flux vs. Temperature $\Phi_v(I_p)/\Phi_v(25^{\circ}C), I_p=8.0 \text{ A}, \text{Pulse duration 20 ms}$



Relative Forward Voltage vs. Temperature $\Delta V = V_f(T_i) - V_f(25^{\circ}C), I_f = 8.0 \text{ A}, \text{Pulse duration 20 ms}$



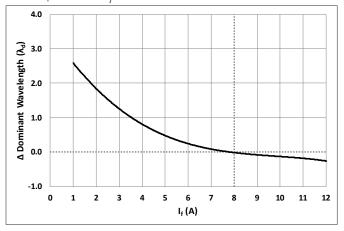


PTM-40X-B/BP

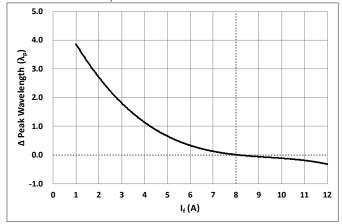
Product Datasheet

Optical and Electrical Characteristics

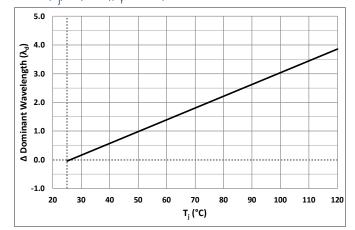
Dominant Wavelength Shift vs. Forward Current $\Delta\lambda = \lambda(I_{r}) - \lambda(8.0 \text{ A}), T_{i} = 25^{\circ}\text{C}$, Pulse duration 20 ms



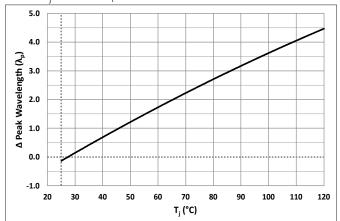
Peak Wavelength Shift vs. Forward Current $\Delta\lambda = \lambda(I_p) - \lambda(8.0 \text{ A}), T_i = 25^{\circ}\text{C}$, Pulse duration 20 ms



Dominant Wavelength Shift vs. Temperature $\Delta \lambda = \lambda(T_{i}) - \lambda(25^{\circ}C), I_{e} = 8.0 \text{ A}, \text{ Pulse duration 20 ms}$



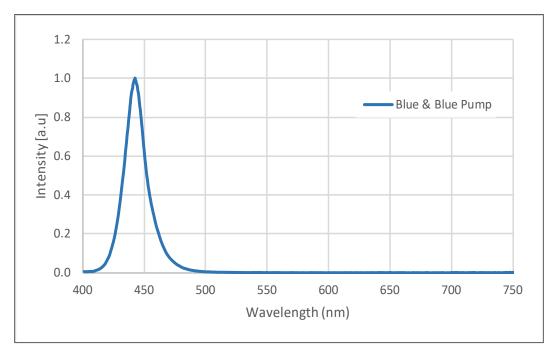
Peak Wavelength Shift vs. Temperature $\Delta \lambda = \lambda(T_{,}) - \lambda(25^{\circ}C), I_{,} = 8.0 \text{ A}, \text{Pulse duration 20 ms}$



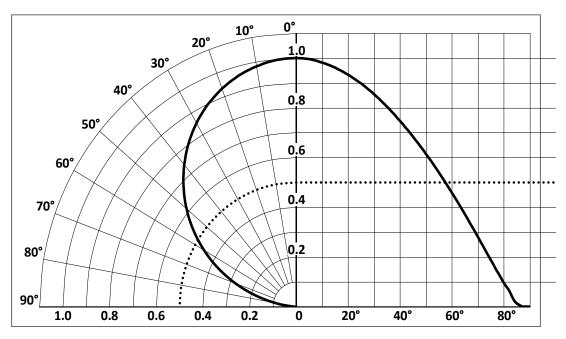


Angular Distribution and Spectrum

Typical Spectrum¹



Typical Angular Distribution²



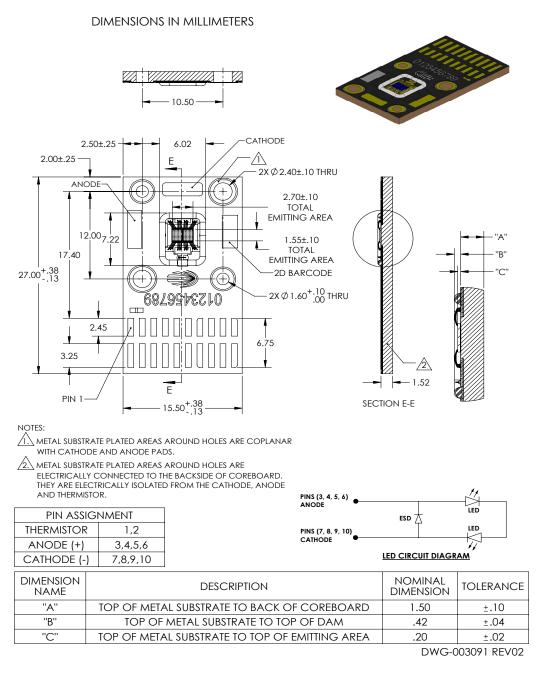
Note 1: Typical spectrum at recommended peak drive current. Please contact Luminus to obtain data in Excel format.

Note 2: For any specific device, slight variations may be expected.

8



Mechanical Dimensions



Note 1: Die Tilt: 1° Maximum, Die Rotation: ±1°

Note 2: Contact within silicone dam area is prohibited

Note 3: Recommended connector: Manufacturer: Tarng-Yu; Part# TU1502WGR-10S-GO-M8-NL-A

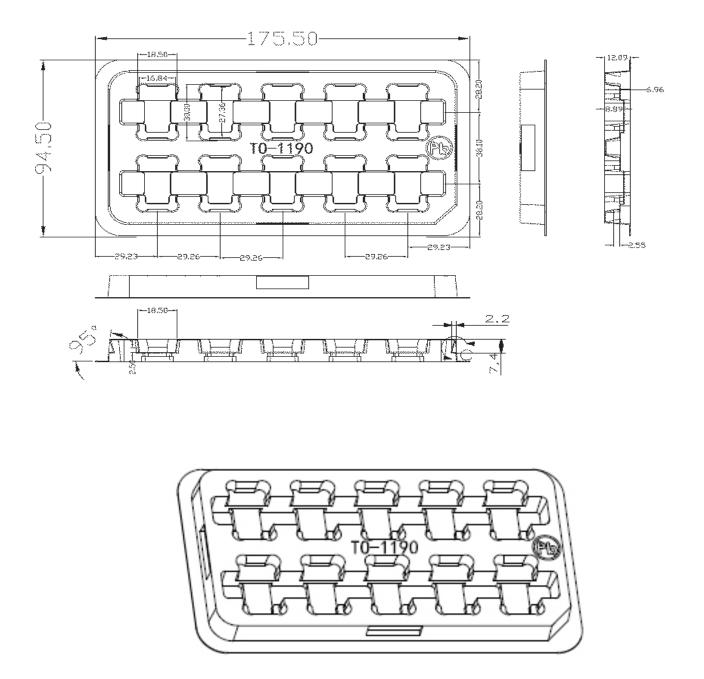
Note 4: Recommended female connector: Manufacturer: Tarng-Yu; Part# TU1502HNO-10; contact terminal part#TU1502TGO-GO

Note 5: LED coreboard backside is electrically isolated

Note 6: LED emitter and wirebond not covered, contact within the silicone dam area is prohibited



Shipping Tray Outline



For detailed drawing of shipping tray, please refer to document TO-1190, available upon request.



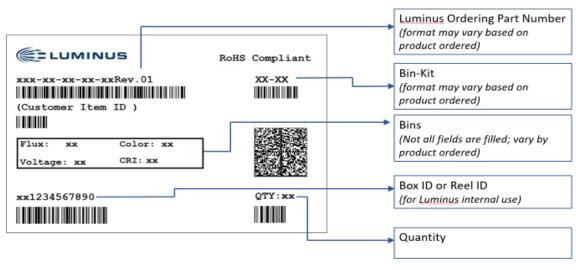
Packing and Shipping Specifications

Packing Specification

Packing Configuration	Qty /Pack	Pack Dimensions (L x W x H, mm)	Gross Weight (kg)
Stack of 5 trays with 10 devices per tray Each pack is enclosed in ESD bag	50	180 x 100 x 40	0.3

Product Label Specification

Label Fields:



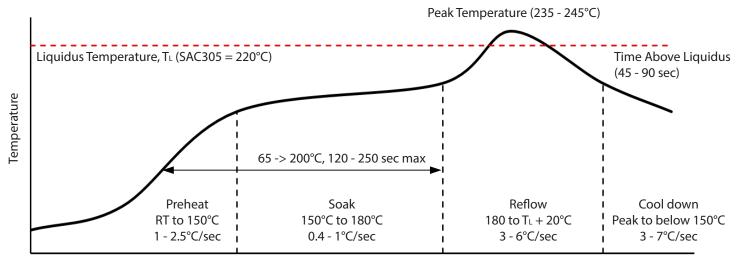
Sample label – for illustration only

Shipping Box

Shipping Box	Quantity	Material	Dimensions (L x W x H, mm)
Carton Box	1-20 packs	S4651	560 x 560 x 200



Soldering Profile



Time

SMT Rework Guideline	Manual Hotplate Reflow Hot Air Gun Reflow		
Heating Time	< 60 sec		
Hotplate Temperature	< 245°C	< 150°C	

Note 1: Product complies to Moisture Sensitivity Level 1 (MSL 1).

Note 2: The numbers in the table are specific to SAC305. Luminus recommends using an SAC305 solder paste with a no-clean flux for RoHS compliant products.

Note 3: During the pick and place process, ensure the pick-up tool does not touch any die components.

Note 4: Use of a multi-zone IR reflow oven with a nitrogen blanket is recommended.

Note 5: Time-temperature profile of the reflow process showing the four functional profile zones are defined in IPC-7801. Temperature is referenced to the center of the PCB.

Note 6: Luminus recommends to use the solder paste data sheet information as a starting point in time-temperature process development.

Note 7: These are general guidelines. Consult the solder paste manufacturer's datasheet for guidelines specific to the alloy and flux combination used in your application. For more information, please refer to:

https://luminusdevices.zendesk.com/hc/en-us/articles/360060306692-How-do-I-Reflow-Solder-Luminus-SMD-Components-

Note 8: For any technical questions about soldering process, please contact Luminus at techsupport@luminus.com.

Note 9: This profile applies when attaching surface mount components.



Notes

Static Electricity

This product is sensitive to static electricity, and care should be taken when handling them. Static electricity or surge voltage will damage the LEDs. It is recommended to wear an anti-electrostatic wristband or anti-electrostatic gloves when handling the LEDs. All devices, equipment and machinery must be properly grounded. It is recommended that measures be taken to isolate LED processing equipment from potential sources of voltage surges.

Reference: APN-002815 Electrical Stress Damage to LEDs and How to Prevent It



History of Changes

Revision	Date	Description of Change		
Rev A	09/21/2020	PTM-40X-B / BP single color datasheet initial draft		
Rev B	02/25/2021	Add product image Add ESD sensitivity Update Rth Update characterization chart		
Rev C	06/08/2023	Update data sheet format Update mechanical drawing Update parametric table spec on page 4		

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